SN74LS85

4-Bit Magnitude Comparator

The SN74LS85 is a 4-Bit Magnitude Camparator which compares two 4-bit words (A, B), each word having four Parallel Inputs (A_0–A_3, B_0–B_3); A_3, B_3 being the most significant inputs. Operation is not restricted to binary codes, the device will work with any monotonic code. Three Outputs are provided: "A greater than B" ($O_{A>B}$), "A less than B" ($O_{A<B}$), "A equal to B" ($O_{A=B}$). Three Expander Inputs, $I_{A>B}$, $I_{A<B}$, $I_{A=B}$, allow cascading without external gates. For proper compare operation, the Expander Inputs to the least significant position must be connected as follows: $I_{A<B}$= $I_{A>B}$ = L, $I_{A=B}$ = H. For serial (ripple) expansion, the $O_{A>B}$, $O_{A<B}$ and $O_{A=B}$ Outputs are connected respectively to the $I_{A>B}$, $I_{A<B}$, and $I_{A=B}$ Inputs of the next most significant comparator, as shown in Figure 1. Refer to Applications section of data sheet for high speed method of comparing large words.

The Truth Table on the following page describes the operation of the SN74LS85 under all possible logic conditions. The upper 11 lines describe the normal operation under all conditions that will occur in a single device or in a series expansion scheme. The lower five lines describe the operation under abnormal conditions on the cascading inputs. These conditions occur when the parallel expansion technique is used.

- Easily Expandable
- Binary or BCD Comparison
- $O_{A>B}$, $O_{A<B}$, and $O_{A=B}$ Outputs Available

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Typ	Max	Unit
V_{CC}	Supply Voltage	4.75	5.0	5.25	V
T_A	Operating Ambient Temperature Range	0	25	70	°C
I_{OH}	Output Current – High			–0.4	mA
I_{OL}	Output Current – Low			8.0	mA

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LOW POWER SCHOTTKY

16 · 1
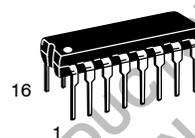
PLASTIC N SUFFIX CASE 648

16 · 1
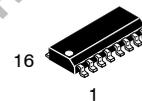
SOIC D SUFFIX CASE 751B

16 · 1
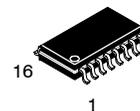
SOEIAJ M SUFFIX CASE 966

ORDERING INFORMATION

Device	Package	Shipping
SN74LS85N	16 Pin DIP	2000 Units/Box
SN74LS85D	SOIC–16	38 Units/Rail
SN74LS85DR2	SOIC–16	2500/Tape & Reel
SN74LS85M	SOEIAJ–16	See Note 1
SN74LS85MEL	SOEIAJ–16	See Note 1

1. For ordering information on the EIAJ version of the SOIC package, please contact your local ON Semiconductor representative.

SN74LS85

CONNECTION DIAGRAM DIP (TOP VIEW)

V_{CC}	A_3	B_2	A_2	A_1	B_1	A_0	B_0
16	15	14	13	12	11	10	9

1	2	3	4	5	6	7	8
B_3	$I_{A<B}$	$I_{A=B}$	$I_{A>B}$	$O_{A>B}$	$O_{A=B}$	$O_{A<B}$	GND
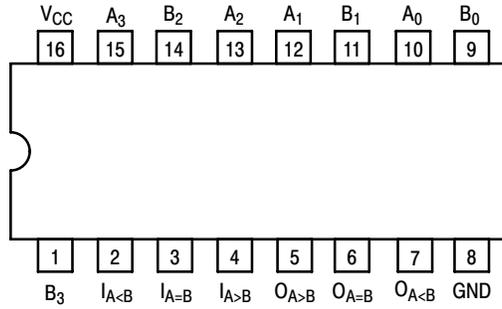
NOTE:
The Flatpak version has the same pinouts (Connection Diagram) as the Dual In-Line Package.

PIN NAMES

		LOADING (Note a)	
		HIGH	LOW
$A_0 - A_3$, $B_0 - B_3$	Parallel Inputs	1.5 U.L.	0.75 U.L.
$I_{A=B}$	A = B Expander Inputs	1.5 U.L.	0.75 U.L.
$I_{A<B}$, $I_{A>B}$	A < B, A > B, Expander Inputs	0.5 U.L.	0.25 U.L.
$O_{A>B}$	A Greater than B Output	10 U.L.	5 U.L.
$O_{A<B}$	B Greater than A Output	10 U.L.	5 U.L.
$O_{A=B}$	A Equal to B Output	10 U.L.	5 U.L.

NOTES:
  a) 1 TTL Unit Load (U.L.) = 40 μA HIGH/1.6 mA LOW.

LOGIC SYMBOL

	10	12	13	15	9	11	14	1	
	A_0	A_1	A_2	A_3	B_0	B_1	B_2	B_3	

4 —	$I_{A>B}$		$O_{A>B}$	— 5
2 —	$I_{A<B}$		$O_{A<B}$	— 7
3 —	$I_{A=B}$		$O_{A=B}$	— 6

V_{CC} = PIN 16
GND = PIN 8

SN74LS85

LOGIC DIAGRAM
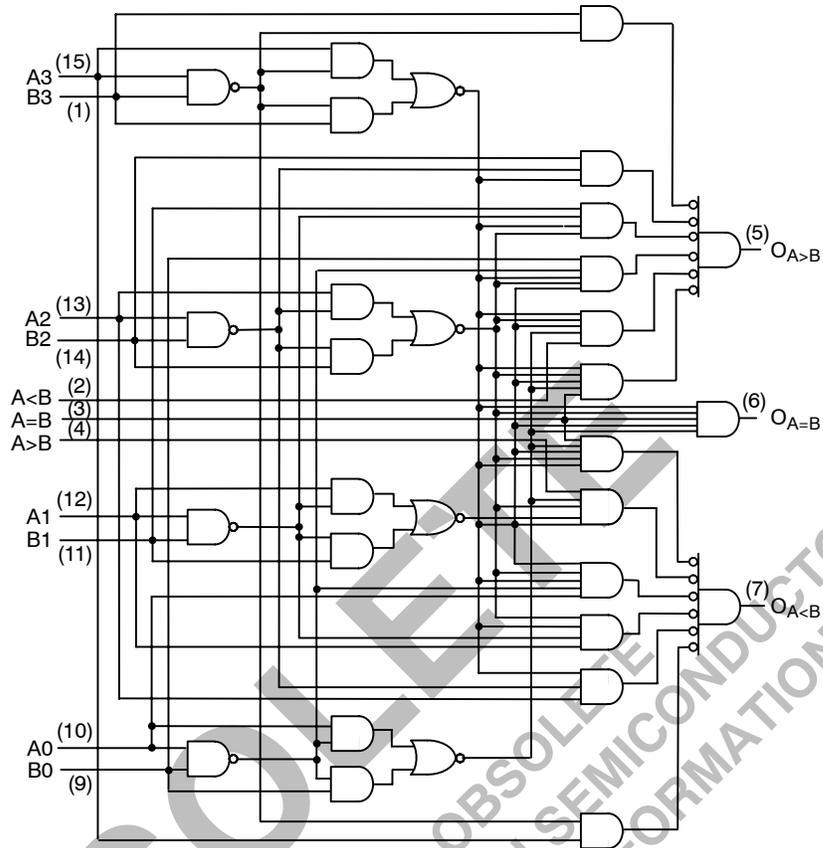
TRUTH TABLE

COMPARING INPUTS				CASCADING INPUTS			OUTPUTS		
A_3,B_3	A_2,B_2	A_1,B_1	A_0,B_0	$I_{A>B}$	$I_{A<B}$	$I_{A=B}$	$O_{A>B}$	$O_{A<B}$	$O_{A=B}$
$A_3>B_3$	X	X	X	X	X	X	H	L	L
$A_3<B_3$	X	X	X	X	X	X	L	H	L
$A_3=B_3$	$A_2>B_2$	X	X	X	X	X	H	L	L
$A_3=B_3$	$A_2<B_2$	X	X	X	X	X	L	H	L
$A_3=B_3$	$A_2=B_2$	$A_1>B_1$	X	X	X	X	H	L	L
$A_3=B_3$	$A_2=B_2$	$A_1<B_1$	X	X	X	X	L	H	L
$A_3=B_3$	$A_2=B_2$	$A_1=B1$	$A_0>B_0$	X	X	X	H	L	L
$A_3=B_3$	$A_2=B_2$	$A_1=B_1$	$A_0<B_0$	X	X	X	L	H	L
$A_3=B_3$	$A_2=B_2$	$A_1=B_1$	$A_0=B_0$	H	L	L	H	L	L
$A_3=B_3$	$A_2=B_2$	$A_1=B_1$	$A_0=B_0$	L	H	L	L	H	L
$A_3=B_3$	$A_2=B_2$	$A_1=B_1$	$A_0=B_0$	X	X	H	L	L	H
$A_3=B_3$	$A_2=B_2$	$A_1=B_1$	$A_0=B_0$	H	H	L	L	L	L
$A_3=B_3$	$A_2=B_2$	$A_1=B_1$	$A_0=B_0$	L	L	L	H	H	L

H = HIGH Level
L = LOW Level
X = IMMATERIAL

SN74LS85
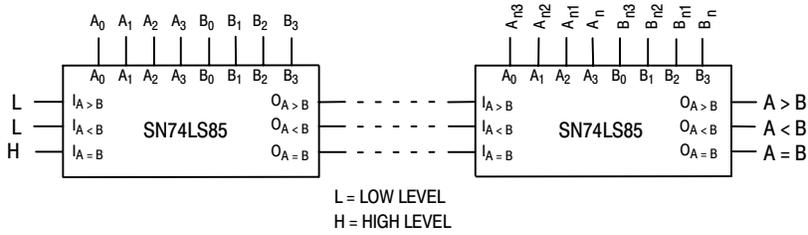
Figure 1. Comparing Two n-Bit Words

APPLICATIONS

Figure 2 shows a high speed method of comparing two 24-bit words with only two levels of device delay. With the technique shown in Figure 1, six levels of device delay result when comparing two 24-bit words. The parallel technique can be expanded to any number of bits, see Table 1.

Table 1

WORD LENGTH	NUMBER OF PKGS.
1 – 4 Bits	1
5 – 24 Bits	2 – 6
25 – 120 Bits	8 – 31

NOTE:
The SN74LS85 can be used as a 5-bit comparator only when the outputs are used to drive the A_0–A_3 and B_0–B_3 inputs of another SN74LS85 as shown in Figure 2 in positions #1, 2, 3, and 4.

MSB = MOST SIGNIFICANT BIT
LSB = LEAST SIGNIFICANT BIT
L = LOW LEVEL
H = HIGH LEVEL
NC = NO CONNECTION
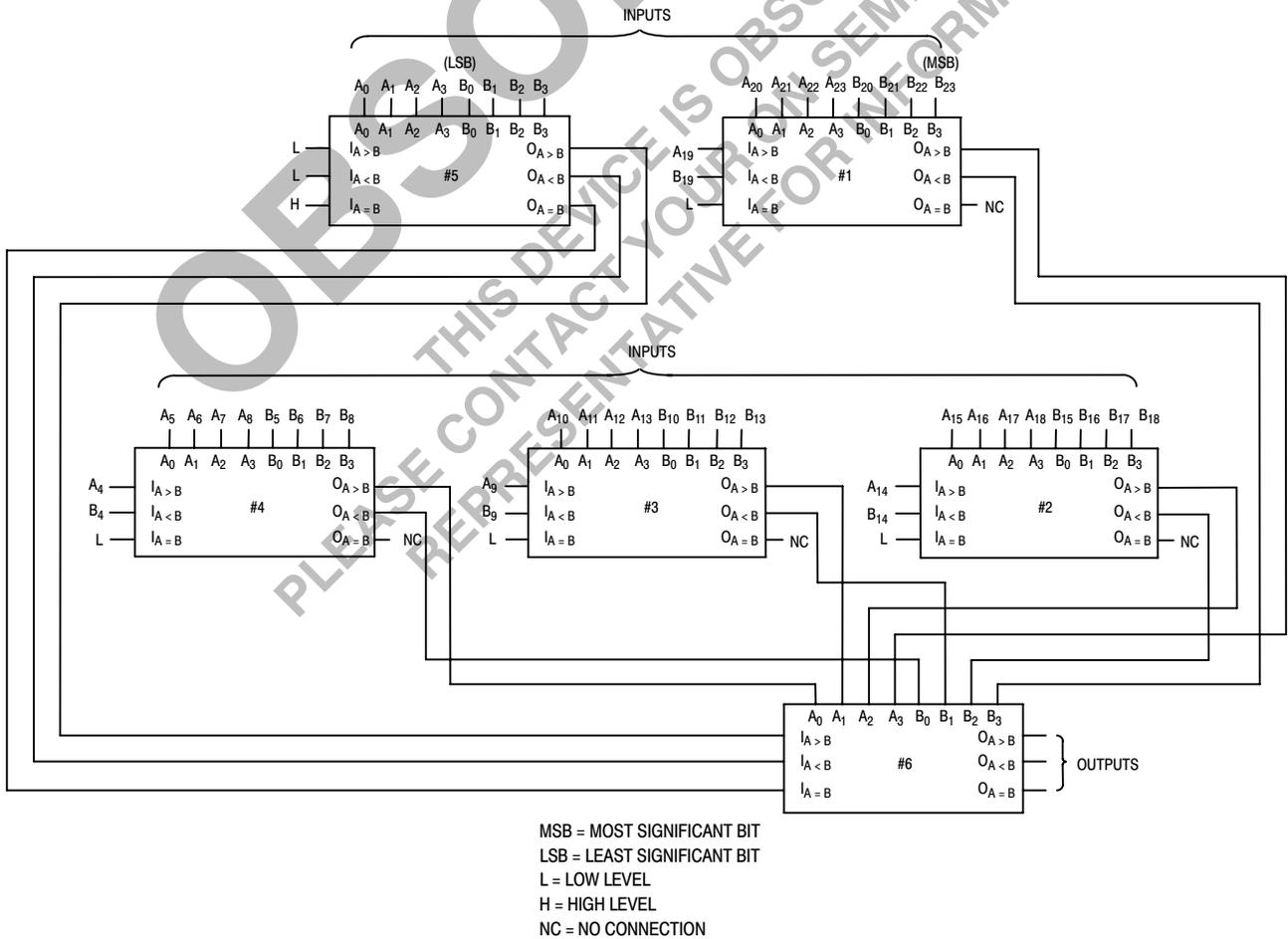
Figure 2. Comparison of Two 24-Bit Words

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

Symbol	Parameter	Min	Typ	Max	Unit	Test Conditions	
V_{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs	
V_{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs	
V_{IK}	Input Clamp Diode Voltage		−0.65	−1.5	V	V_{CC} = MIN, I_{IN} = − 18 mA	
V_{OH}	Output HIGH Voltage	2.7	3.5		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table	
V_{OL}	Output LOW Voltage		0.25	0.4	V	I_{OL} = 4.0 mA	V_{CC} = V_{CC} MIN, V_{IN} = V_{IL} or V_{IH} per Truth Table
			0.35	0.5	V	I_{OL} = 8.0 mA	
I_{IH}	Input HIGH Current A < B, A > B Other Inputs			20 60	µA	V_{CC} = MAX, V_{IN} = 2.7 V	
	A < B, A > B Other Inputs			0.1 0.3	mA	V_{CC} = MAX, V_{IN} = 7.0 V	
I_{IL}	Input LOW Current A < B, A > B Other Inputs			−0.4 −1.2	mA	V_{CC} = MAX, V_{IN} = 0.4 V	
I_{OS}	Output Short Circuit Current (Note 2)	−20		−100	mA	V_{CC} = MAX	
I_{CC}	Power Supply Current			20	mA	V_{CC} = MAX	

2. Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25°C, V_{CC} = 5.0 V)

| Symbol	Parameter	Min	Typ	Max	Unit	Test Conditions
t_{PLH} t_{PHL}	Any A or B to A < B, A > B		24 20	36 30	ns	
t_{PLH} t_{PHL}	Any A or B to A = B		27 23	45 45	ns	
t_{PLH} t_{PHL}	A < B or A = B to A > B		14 11	22 17	ns	V_{CC} = 5.0 V C_L = 15 pF
t_{PLH} t_{PHL}	A = B to A = B		13 13	20 26	ns	
t_{PLH} t_{PHL}	A > B or A = B to A < B		14 11	22 17	ns	

AC WAVEFORMS
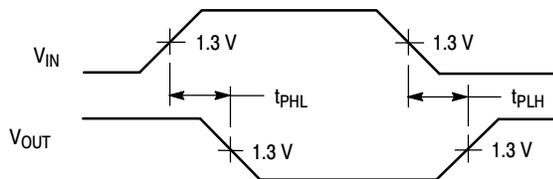
Figure 3.
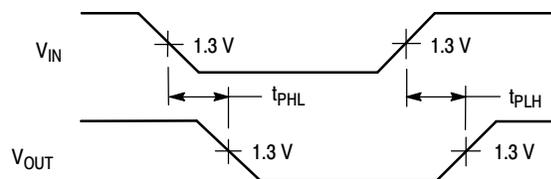
Figure 4.

## PACKAGE DIMENSIONS

N SUFFIX
PLASTIC PACKAGE
CASE 648–08
ISSUE R
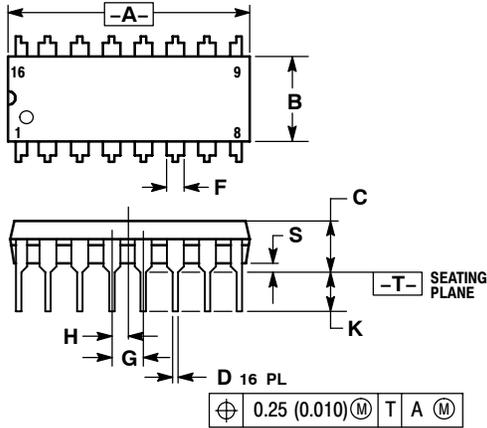
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.740	0.770	18.80	19.55
B	0.250	0.270	6.35	6.85
C	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100 BSC		2.54 BSC	
H	0.050 BSC		1.27 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0 °	10 °	0 °	10 °
S	0.020	0.040	0.51	1.01

D SUFFIX
PLASTIC SOIC PACKAGE
CASE 751B–05
ISSUE J
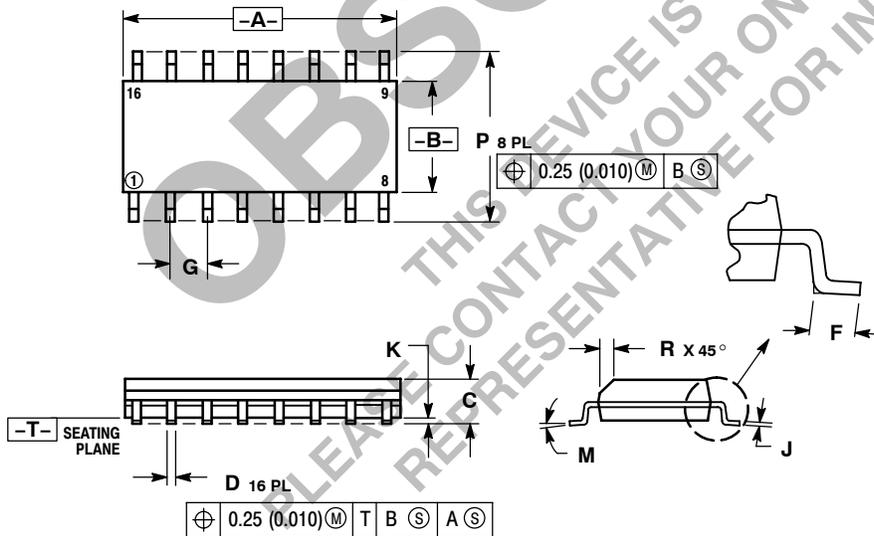
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0 °	7 °	0 °	7 °
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

PACKAGE DIMENSIONS

M SUFFIX
SOEIAJ PACKAGE
CASE 966–01
ISSUE O
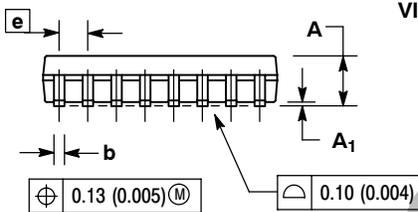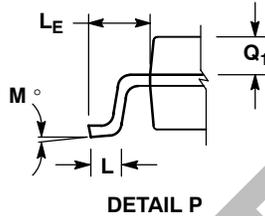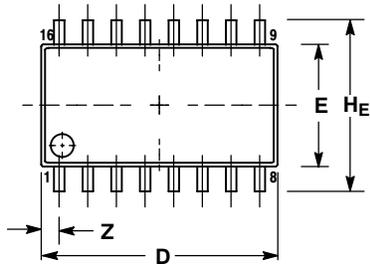
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	---	2.05	---	0.081
A$_1$	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
c	0.18	0.27	0.007	0.011
D	9.90	10.50	0.390	0.413
E	5.10	5.45	0.201	0.215
e	1.27 BSC		0.050 BSC	
H$_E$	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
L$_E$	1.10	1.50	0.043	0.059
M	0 °	10 °	0 °	10 °
Q$_1$	0.70	0.90	0.028	0.035
Z	---	0.78	---	0.031

DETAIL P

VIEW P

OBSOLETE

THIS DEVICE IS OBSOLETE.
PLEASE CONTACT YOUR ON SEMICONDUCTOR
REPRESENTATIVE FOR INFORMATION.